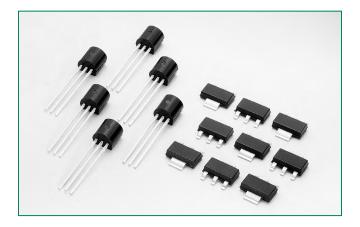


L01 Series





Main Features

Symbol	Value	Unit
I _{T(RMS)}	1	А
V _{DRM} /V _{RRM}	400 to 800	V
l _{GT}	3 to 10	mA

Additional Information







Resources



Description

New 1 Amp bi-directional solid state switch series offering direct interface to microprocessor drivers in economical TO-92 and surface mount packages. The die voltage blocking junctions are glass-passivated to ensure long term reliability and parametric stability.

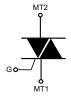
Features

- RoHS compliant and Halogen-Free
- Blocking voltage (V_{DRM}) capability — up to 800V
- Surge capability > 10Amps
- Static dv/dt > 20 Volts/ µsec
- Thru hole and surface mount packages

Applications

The L01 EV Series is especially designed for white goods applications such as valve controls in washing machines as well as replacement of mechanical and hybrid relays where long life is required.

Schematic Symbol



Absolute Maximum Ratings

Symbol	Parameter	Value	Unit		
	RMS on-state current	TO-92	T _C = 50°C	1.0A	А
I _{T(RMS)}	(full sine wave)	SOT-223	T _L = 90°C	I.UA	A
	Non repetitive surge peak on-state current	TO-92	F = 50 Hz	10	А
TSM	(Single cycle, T _J initial = 25°C)	SOT-223	F = 60 Hz	12	
l²t	l²t Value for fusing	$t_{p} = 10 \text{ ms}$	F = 50 Hz	0.50	A ² s
11	i t value for fusing	$t_p = 8.3 \text{ ms}$	F = 60 Hz	0.59	A 5
di/dt	Critical rate of rise of on-state current $I_{G} = 2 \times I_{GT}$	TO-92 SOT-223	T _J = 125°C	20	A/μs
I _{GTM}	Peak gate current	t _p = 10 μs	T _J = 125°C	1	А
P _{G(AV)}	Average gate power dissipation $T_J = 125^{\circ}\text{C}$			0.1	W
T _{stg}	Storage junction temperature range	-40 to 150	°C		
T _J	Operating junction temperature range			-40 to 125	°C

Specifications are subject to change without notice.

Teccor® brand Thyristors EV Series 1 Amp Sensitive Triacs

Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test	! ()uadrant!			Value		Unit
Syllibol	Description	Conditions	Quadrant	Limit	L0103xy	L0107xy	L0109xy	Offic
I _{GT}	DC Gate Trigger Current	V _D = 12V	I – II – III IV	MAX.	3 5	5 7	10 10	mA
V _{GT}	DC Gate Trigger Voltage	$R_L = 60 \Omega$	ALL	MAX.	_	1.3	_	V
I _H	Holding Current	Gate	Open	MAX.	7	10	10	mA
dv/dt	Critical Rate-of-Rise of Off-State Voltage	$T_J = 110^{\circ}\text{C}$ $V_D = V_{DRM}$ Exponential Waveform Gate Open		MIN.	10	20	50	V/µs
(dv/dt)c	Critical Rate-of-Rise of Commutating Voltage	(di/dt)c = 0.54A/ms T _J = 110°C		MIN.	0.5	1.0	2.0	V/µs
T _{gt}	Turn-On Time	PW =	25mA : 15µs 2A (pk)	MAX.	2.0	2.0	2.0	μs

Note: x = voltage, y = package

Static Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Limit	Value	Unit
V _{TM}	Peak On-State Voltage	I _{TM} = 1.4A (pk)	MAX	1.60	V
I _{DRM}	Off-State Current, Peak Repetitive	$V_D = V_{DRM} T_J = 25^{\circ}C$	NAAV	5	μА
		$V_D = V_{DRM} T_J = 125$ °C	MAX	500	μΑ

Thermal Resistances

Symbol	Description	Test Conditions		Value	Unit
D	lunction to coop (AC)	1 100 1	TO-92	50	°C A A /
R _{th(j-c)}	Junction to case (AC)	$I_{T} = 1.0A_{(RMS)}^{1}$	SOT-223	23	°C/W
D	Junction to ambient	1 - 100 1	TO-92	100	°C/W
$R_{\text{th(j-a)}}$		$I_T = 1.0A_{(RMS)}^{1}$	SOT-223	55	C/VV

¹ 60Hz AC resistive load condition, 100% conduction.



Figure 1: Definition of Quadrants

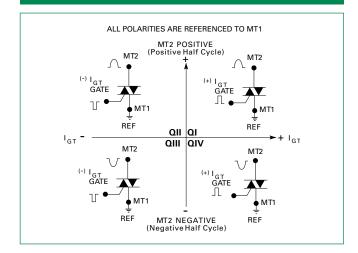


Figure 3: Normalized DC Holding Current vs. Junction Temperature

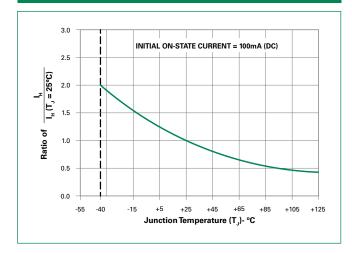
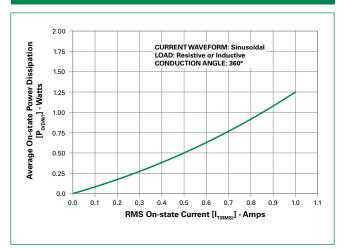


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current



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Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature

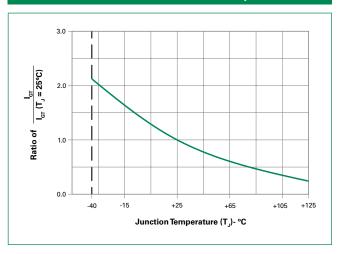


Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature

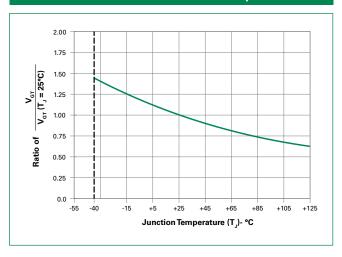
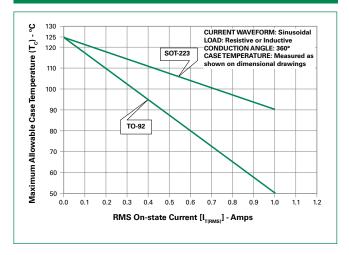
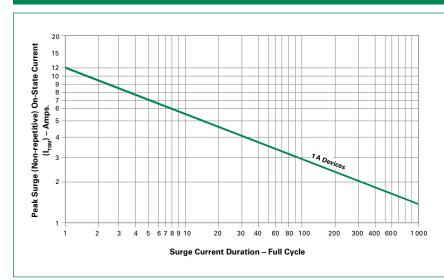


Figure 6: Maximum Allowable Case Temperature vs. On-State Current







Supply Frequency: 60Hz Sinusoidal

Load: Resistive RMS On-State Current [I_{TRIMS]}]: Max Rated Value at Specific Case Temperature

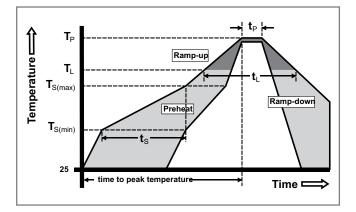
Notes:

- 1. Gate control may be lost during and immediately
- following surge current interval.

 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Soldering Parameters

Reflow Co	ndition	Pb – Free assembly	
-Temperature Min (T _{s(min)})		150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ra (T _L) to pea	amp up rate (Liquidus Temp) k	5°C/second max	
$T_{S(max)}$ to T_{L}	- Ramp-up Rate	5°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
nellow	-Time (min to max) (t _s)	60 – 150 seconds	
PeakTemp	erature (T _P)	260+ ^{0/-5} °C	
Time within 5°C of actual peak Temperature (t _n)		20 - 40 seconds	
Ramp-dov	vn Rate	5°C/second max	
Time 25°C	to peak Temperature (T _P)	8 minutes Max.	
Do not exc	ceed	280°C	





Physical Specifications

Terminal Finish	100% Matte Tin-plated.	
Body Material	UL recognized epoxy meeting flammability classification 94V-0.	
Lead Material	Copper Alloy	

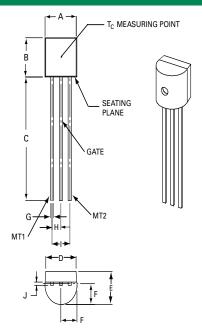
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

Test	Specifications and Conditions
AC Blocking	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031, 1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E

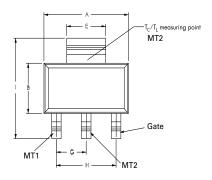
Dimensions — TO-92 (E Package)

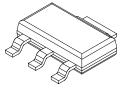


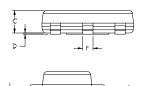
Dimensions	Inc	hes	Millimeters		
Dimensions	Min	Max	Min	Max	
А	0.175	0.205	4.450	5.200	
В	0.170	0.210	4.320	5.330	
С	0.500		12.70		
D	0.135		3.430		
Е	0.125	0.165	3.180	4.190	
F	0.080	0.105	2.040	2.660	
G	0.016	0.021	0.407	0.533	
Н	0.045	0.055	1.150	1.390	
1	0.095	0.105	2.420	2.660	
J	0.015	0.020	0.380	0.500	



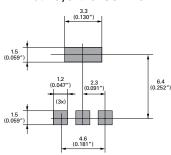
Dimensions – SOT-223







Pad Layout for SOT-223



Dimensions in Millimeters (Inches)

Dimensions	Inches			Millimeters		
Dimensions	Min	Тур	Max	Min	Тур	Max
А	0.248	0.256	0.264	6.30	6.50	6.70
В	0.130	0.138	0.146	3.30	3.50	3.70
С	_	_	0.071	_	_	1.80
D	0.001	_	0.004	0.02	_	0.10
Е	0.114	0.118	0.124	2.90	3.00	3.15
F	0.024	0.027	0.034	0.60	0.70	0.85
G	_	0.090	_	_	2.30	_
Н	_	0.181	_	_	4.60	_
I	0.264	0.276	0.287	6.70	7.00	7.30
J	0.009	0.010	0.014	0.24	0.26	0.35
K			10° l	MAX		

Product Selector

D (N)	V. II	Gate Sensitivity Quadrants		
Part Number	Voltage		IV	Package
L0103DE	400 V	3 mA	5 mA	TO-92
L0103ME	600 V	3 mA	5 mA	TO-92
L0103NE	800 V	3 mA	5 mA	TO-92
L0103DT	400 V	3 mA	5 mA	SOT-223
L0103MT	600 V	3 mA	5 mA	SOT-223
L0103NT	800 V	3 mA	5 mA	SOT-223
L0107DE	400 V	5 mA	7 mA	TO-92
L0107ME	600 V	5 mA	7 mA	TO-92
L0107NE	800 V	5 mA	7 mA	TO-92
L0107DT	400 V	5 mA	7 mA	SOT-223
L0107MT	600 V	5 mA	7 mA	SOT-233
L0107NT	800 V	5 mA	7 mA	SOT-233
L0109DE	400 V	10 mA	10 mA	TO-92
L0109ME	600 V	10 mA	10 mA	TO-92
L0109NE	800 V	10 mA	10 mA	TO-92
L0109DT	400 V	10 mA	10 mA	SOT-223
L0109MT	600 V	10 mA	10 mA	SOT-223
L0109NT	800 V	10 mA	10 mA	SOT-223



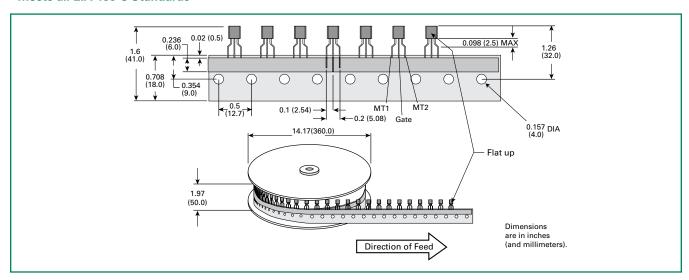
Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
L01xxyE	L01xxyE	0.217 g	Bulk	2500
L01xxyEAP	L01xxyE	0.217 g	Ammo Pack	2000
L01xxyERP	L01xxyE	0.217 g	Tape & Reel	2000
L01xxyTRP	L01xxyT	0.120 g	Tape & Reel	1000

Note: xx = gate sensitivity, y = voltage

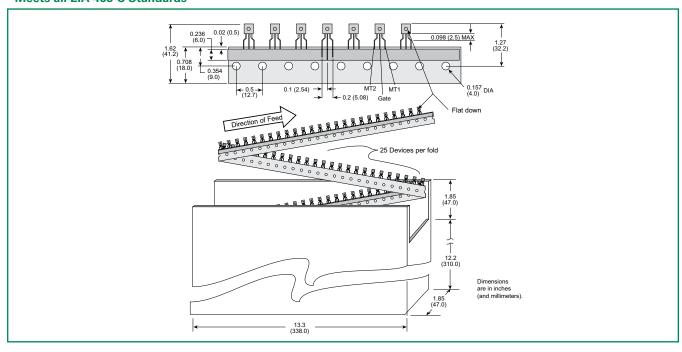
TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-C Standards



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Revised: 05/02/16



SOT-223 Reel Pack (RP) Specifications Ø1.5 mm -4 mm 8 mm 2 mm MT2 1.75 mm \oplus \oplus \oplus 5.5 mm 12 mm GATE MT1-/ MT2 180 mm 13 mm Abor Hole Diameter Ì 13.4 mm

L01xx x xxxx TRIAC SERIES **PACKING TYPE** Blank: Bulk Pack : Reel Pack (TO-92) : Embossed Carrier Pack CURRENT **01**: 1A (SOT-223) : Ammo Pack (TO-92) ΑP PACKAGE TYPE SENSITIVITY & TYPE E: TO-92 T: SOT-223 03: 3, 3, 5mA Triac 07: 5, 5, 5, 7mA Triac 09: 10, 10, 10, 10mA Triac VOLTAGE **D**: 400V M: 600V

N: 800V

Part Numbering System

TO92 Line 1 = Littelfuse Part Number Line2 = continuation...Littelfuse Part Number Y = Last Digit of Calendar Year M = Letter Month Code (A-L for Jan-Dec) L = Location Code DD = Calendar Date

Part Marking System